AMENDMENTS TO THE SPECIFICATION

Please replace the paragraph at page 3, lines 11-19, with the following amended paragraph:

The bar 200 bars 202 are mutually separated by spaces 201 having a width W_e. The channel 230 is covered and in contact over a surface S₂ (not shown in FIG. 2) with a gate 240. The extent of the surface S₂ influences the value of the threshold voltage of the transistor. It is preferably as small as possible so as to limit the consumption of the transistor, but must be large enough to be capable of ensuring a good current level in the channel 230.

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